Ī	Hits	Search Text	DB	Time at a second
Number	nics	Scarch Text	DB DB	Time stamp
5	1		USPAT	2003/02/24
	1			09:14
6	1		USPAT .	2003/02/24
7	1		IICDAM	09:15
'	1		USPAT	2003/02/24
8	1	("6376896").PN.	USPAT	2003/02/24
		, , , , , , , , , , , , , , , , , , , ,	OBIAI	09:26
9	7	("4210996" "4496935" "5128731"	USPAT	2003/02/24
		"5235312" "5554873" "5554989"		09:27
	_	"5666007").PN.		
-	1	"5081515".PN.	USPAT	2003/02/21
	1	"5525530".PN.	******	14:43
	1	J323330 .FN.	USPAT	2003/02/21
_ `	1	"5119162".PN.	USPAT	14:43
	-		JULAI	14:52
·	1	"5148255".PN.	USPAT	2003/02/21
				14:52
	1	"5169794".PN.	USPAT	2003/02/21
_		HE1 CO704H DY		14:52
-	1	"5169794".PN.	USPAT	2003/02/21
_	1	"5216217".PN.	Habba	14:52
	1	3210217 .FM.	USPAT	2003/02/21 14:52
-	597	cmos same resistor and p near2 gate	USPAT	2003/02/23
		· · · · · · · · · · · · · · · · · · ·	John	15:17
_	3	cmos same resistor and p adj doped near2	USPAT	2003/02/23
	·	gate		12:47
_	795	gate adj electrode near2 "p-type"	USPAT	2003/02/23
_	155	gate adj electrode near2 "p-type" and		13:15
	133	resistor	USPAT	2003/02/23
_	31	gate adj electrode near2 "p-type" and	US-PGPUB;	13:31 2003/02/23
		resistor	EPO; JPO;	14:02
-	·		DERWENT;	
	_	(457404544)	IBM_TDB	
-	1	("5710454").PN.	USPĀT	2003/02/23
	3	complementary adj fet adj devices	TDM MDD	14:03
		comprementary adj tet adj devices	IBM_TDB	2003/02/23
-	1	"p-resistor" and "n-resistor" and	USPAT;	2003/02/23
		transistor and voltage adj dividing adj	US-PGPUB;	15:21
		circuit	EPO; JPO;	
ļ			DERWENT;	
i		War and the state of the state	IBM_TDB	
-	2	"p-resistor" and "n-resistor" and transistor	USPAT;	2003/02/23
		CLANSISTOF	US-PGPUB;	15:21
	1		EPO; JPO; DERWENT;	
			IBM TDB	· -
-	59	p near1 resistor and n near1 resistor and	USPAT;	2003/02/24
ļ		transistor	US-PGPUB;	09:26
	1		EPO; JPO;	'>
	ļ		DERWENT;	
			IBM_TDB	

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